2D Materials for **Future Electronics**

February 19-20, 2024

Super C | RWTH Aachen University Aachen, Germany

Monday, February 19

12:00 - 13:00 Registration & Lunch

2D Materials for more Moore

13:00 – 13:15	Max Lemme (RWTH & AMO)
	Opening

13:15 – 13:45	Frank Schwierz (TU IIImenau)
	2D TMDC MOSFETs - An Option
	to Delay "Forever"?

13:45 – 14:15	Theresia Knobloch (TU Wien)
	Gate Insulators for Ultra-Scaled
	2D Transistors

	ZD Transistors
14:15 - 14:45	Roman Sordan (Politecnico di
	Milano)

Ultra-scaled transistors based on two-dimensional materials

14:45 - 15:00Eike Icking (RWTH)

Ultra-steep slope cryogenic FETs based on bilayer graphene

15:00 - 15:15Taoufig Ouai (RWTH)

Benchmarking Boron Nitride -Crystals and films for integration into graphene-based van der Waals heterostructures

15:15 – 16:00 Coffee Break

Electronics based on TMDCs

16:00 – 16:15	Gordon Rinke (AMO)	
	2D-EPL status update	
16:15 – 16:30	Mindaugas Lukosius (iHP)	
	Introduction to the 2D-EPL's	
	fifth MPW run	-
16:30 - 17:00	Quentin Smets (imec)	5
	Pathfinding TMD channel	2
	deposition with a flexible fab	2
	integration platform	Ç
17:00 - 17:30	Michael Heuken (AIXTRON)	
	Recent progress in MOCVD of	

Recent progress in MOCVD of

TMDC

17:30 - 18:00Q&A

18:00 – 21:00 Poster session & Dinner









Tuesday, February 20

2D Materials for more than Moore

09:00 - 09:15	Daniel Neumaier (AMO &
	University of Wuppertal)
	The ORIGENAL project

Dmitry Polyushkin (TU Wien) 09:15 - 9:45Recent progress on 2D

semiconductor FETs

09:45 - 10:15Agata Piacentini (AMO)

Flexible CMOS logic based on

TMDC 2D materials

10:15 - 10:45Gianluca Fiori (Università di Pisa)

2DMs for advanced devices and

applications

10:45 – 11:00 **Eros Reato** (RWTH)

Nanoscale MoS2 FETs on polyimide for RF operation

11:00 - 11:30 Coffee break

2D Materials for Neuromorphic

computing	
11:30 - 12:00	Adrian Ionescu (EPFL)
	2D ferroelectric synapses for
	neuromorphic computing
12:00 - 12:30	Andras Kis (EPFL)
	Large-scale Integrated Circuits
	with 2D MoS2 for Neuromorph

Computing

Karl Magnus Persson (VTT) 12:30 - 13:00Holistic Approaches for 3D Integration of a Post-CMOS Sensing and Computing Platform

13:00 - 13:15Sofia Cruces (RWTH)

> Forming-free threshold resistive switching in lateral 2D MoS₂-

based devices

13:15 - 13:30Lukas Völkel (RWTH)

Current Conduction Mechanisms in Hexagonal Boron Nitridebased Threshold Memristors

13:30 – 14:30 Light lunch & closing

15:00 - 16:00Silvia Conti (Springer-Nature) Scientific Publishing

















With the financial support of:













